## NSN 5962-01-249-9744

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View Online at https://aerobasegroup.com/nsn/5962-01-249-9744 **Body Length:** 0.640 inches **Body Width:** Between 0.360 inches and 0.420 inches **Body Height:** Between 0.045 inches and 0.090 inches **Maximum Power Dissipation Rating:** 1.02 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Schottky and bipolar and programmable and monolithic **Inclosure Material:** Ceramic or metal **Inclosure Configuration:** Flat pack **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 14 input

**Case Outline Source And Designator:** 

F-6 mil-m-38510

**Terminal Surface Treatment:** 

Solder

## **Voltage Rating And Type Per Characteristic:**

-0.5 volts power source and 7.0 volts power source

## **Time Rating Per Chacteristic:**

100.00 nanoseconds propagation delay time, low to high level output and 100.00 nanoseconds propagation delay time, high to low level output

**Memory Device Type:** 

Rom

**Test Data Document:** 

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

**Terminal Type And Quantity:** 

24 flat leads

Shelf Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

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